

DRD1230F40

Rectifier Diode

DS5978-1 January 2011 (LN27997)

FEATURES

- Double Side Cooling
- High Surge Capability

KEY PARAMETERS

V_{RRM}	4000V
I _{F(AV)}	1225A
I _{FSM}	25000A

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V _{RRM} V	Conditions
DRD1230F40 DRD1230F36 DRD1230F30	4000 3600 3000	$V_{RSM} = V_{RRM} + 100V$

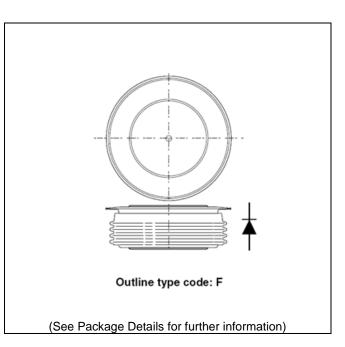


Fig. 1 Package outline

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DRD1230F36 for a 3600V device

CURRENT RATINGS

$T_{\text{case}} = 75^{\circ}\text{C}$ unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units		
Double Si	Double Side Cooled					
$I_{F(AV)}$	Mean forward current	Half wave resistive load	1594	А		
I _{F(RMS)}	RMS value	-	2504	А		
I _F	Continuous (direct) on-state current	-	2295	А		
Single Side Cooled (Anode side)						
I _{F(AV)}	Mean forward current	Half wave resistive load	1144	Α		
I _{F(RMS)}	RMS value	-	1797	Α		
I _F	Continuous (direct) on-state current	-	1553	Α		

T_{case} = 100°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units			
Double Si	Double Side Cooled						
I _{F(AV)}	Mean forward current	Half wave resistive load	1225	А			
I _{F(RMS)}	RMS value	-	1923	Α			
I _F	Continuous (direct) on-state current	-	1720	Α			
Single Side Cooled (Anode side)							
I _{F(AV)}	Mean forward current	Half wave resistive load	820	Α			
I _{F(RMS)}	RMS value	-	1287	А			
I _F	Continuous (direct) on-state current	-	1050	А			

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 150°C	20.0	kA
l ² t	I ² t for fusing	$V_R = 50\% V_{RRM} - \frac{1}{4}$ sine	2.0	MA ² s
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 150°C	25.0	kA
l ² t	I ² t for fusing	$V_R = 0$	3.125	MA ² s

THERMAL AND MECHANICAL RATINGS

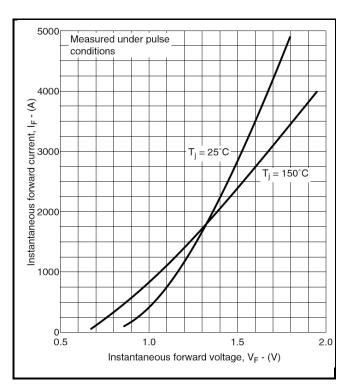
Symbol	Parameter	Test Conditions		Min.	Max.	Units
R _{th(j-c)}	Thermal resistance – junction to case	Double side cooled	DC	-	0.022	°C/W
		Single side cooled	Anode DC	-	0.038	°C/W
			Cathode DC	-	0.052	°C/W
R _{th(c-h)}	Thermal resistance – case to heatsink	Clamping force 19.5kN	Double side	-	0.004	°C/W
		(with mounting compound)	Single side	-	0.008	°C/W
T_{vj}	Virtual junction temperature	On-state (conducting)		-	160	°C
		Reverse (blocking)		-	150	°C
T _{stg}	Storage temperature range			-55	175	°C
F _m	Clamping force			18	22	kN

3/7

CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V _{FM}	Forward voltage	At 3400A peak, T _{case} = 25°C	-	1.6	V
I _{RM}	Peak reverse current	At V _{RRM} , T _{case} = 150°C	-	75	mA
Qs	Total stored charge	$I_F = 2000A$, $dI_{RR}/dt = 3A/\mu s$	-	3500	μC
Irr	Peak reverse recovery current	$T_{case} = 150$ °C, $V_R = 100$ V	-	110	Α
V_{TO}	Threshold voltage	At T _{vj} = 150°C	-	0.82	V
r _T	Slope resistance	At T _{vj} = 150°C	-	0.29	mΩ

CURVES



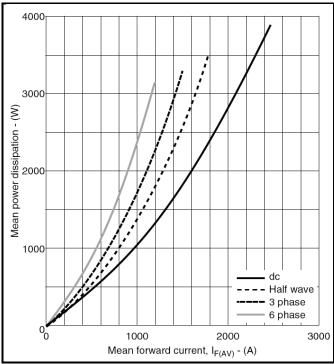


Fig.2 Maximum (limit) on-state characteristics

Fig.3 Dissipation curves

 V_{TM} EQUATION

 $V_{TM} = A + Bln (I_T) + C.I_T + D.\sqrt{I_T}$

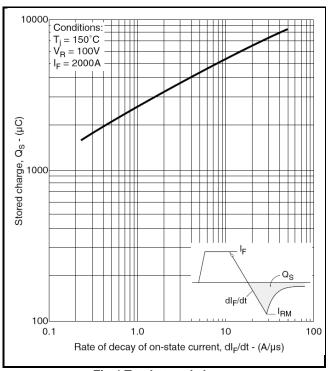
Where A = 0.658789

B = -0.01706

C = 0.000194

D = 0.010358

these values are valid for $T_i = 150$ °C for $I_F 500$ A to 5000A



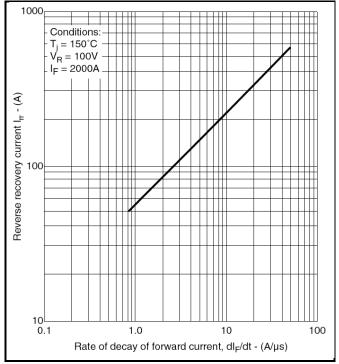
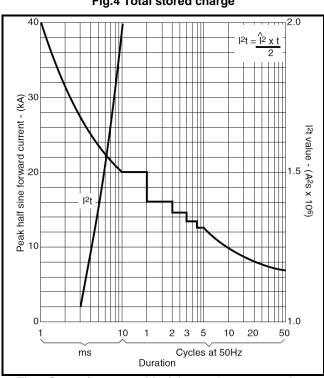
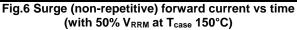


Fig.4 Total stored charge







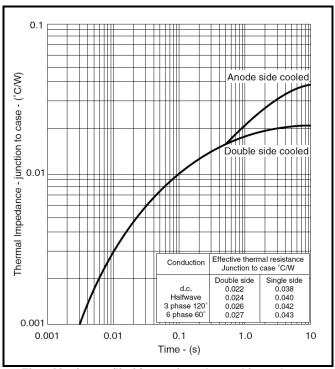
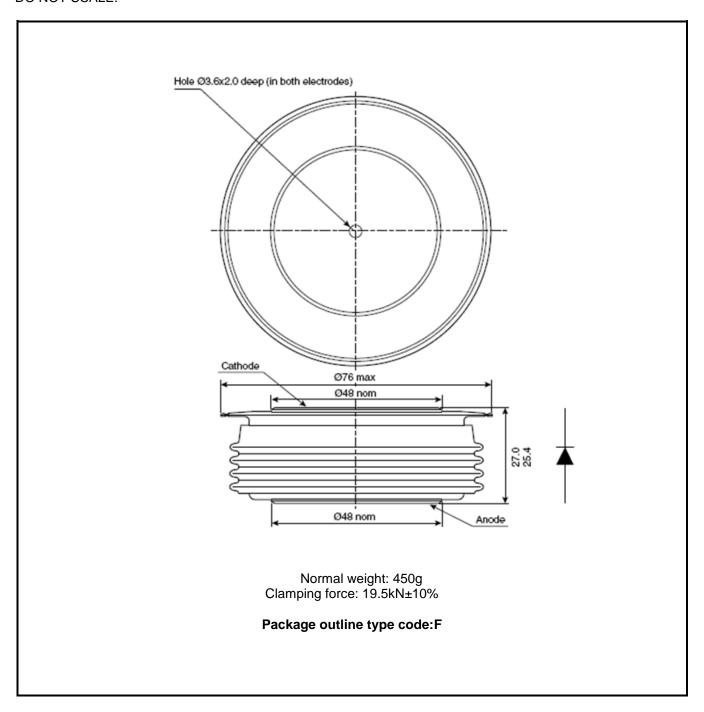


Fig.7 Maximum (limit) transient thermal impedancejunction to case

PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



Note:

Some packages may be supplied with gate and or tags.

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